

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	80124	semiconductor and cmos	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/01 09:25
L2	2206	1 and (work adj function)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/01 09:25
L3	73	2 and (tan or (tantalum adj nitride)) and (mon or (molybdenum adj nitride))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/01 09:31
L4	573	2 and (ta or tantalum) and (tan or (tantalum adj nitride))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/01 09:34
L5	14	2 and (mosi or (molybdenum adj silicide)) and (mon or (molybdenum adj nitride))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/01 09:45